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## Vanishing thermal equilibration for hole-conjugate fractional quantum Hall states in graphene

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Transport through edge channels is responsible for conduction in quantum Hall (QH) phases. Robust quantized values of charge and thermal conductances dictated by bulk topology appear when equilibration processes become dominant. We report on measurements of electrical and thermal conductances of integer and fractional QH phases, realized in hexagonal boron nitride encapsulated graphite-gated bilayer graphene (BLG) devices for both electron and hole doped sides with different valley and orbital symmetries. Remarkably, for complex edges at filling factors  $\nu = \frac{5}{3}$  and  $\frac{8}{3}$ , closely related to the paradigmatic hole-conjugate  $\nu = \frac{2}{3}$  phase, we find quantized thermal conductance whose values  $(3\kappa_0T$  respectively  $4\kappa_0T$ , where  $\kappa_0T$  is the thermal conductance quantum) are markedly inconsistent with the values dictated by topology  $(1\kappa_0T \text{ and } 2\kappa_0T, \text{ respectively})$ . The measured thermal conductance values remain insensitive to different symmetries suggesting its universal nature. Our findings are supported by a theoretical analysis, which indicates that whereas electrical equilibration at the edge is established over a finite length scale, the thermal equilibration length diverges for strong electrostatic interaction. Our results elucidate the subtle nature of crossover from coherent, mesoscopic to topology-dominated transport.

According to the bulk-edge correspondence principle [1–3], certain characteristics of gapless edge modes are constrained by the topological order in the gapped bulk. This turns out to be a subtle issue for hole-conjugate fractional quantum Hall (FQH) phases, whose edges are complex, i.e., hosting counter-propagating modes:  $n_d$ moving downstream (the direction defined by semiclassical skipping orbits at the edge) and  $n_u$  moving upstream (opposite to downstream). The quantized twoterminal electrical conductance for these states has been predicted to be  $G = \nu \frac{e^2}{h}$ , while the thermal conductance is  $G_Q = |n_d - n_u| \kappa_0 T$ . Here,  $\nu$  is the bulk Landaulevel filling factor,  $\kappa_0 = \frac{\pi^2 k_B^2}{3h}$ ,  $k_B$  is the Boltzmann constant,  $h$  is the Planck constant, and  $T$  is the temperature [4–6]. Observing the quantization of G and  $G_Q$  requires full equilibration of the counter-propagating edge modes [7, 8].

The paradigmatic example of a complex edge occurs at  $\nu = \frac{2}{3}$  and consists of counter-propagating 1 (downstream) and  $\frac{1}{3}$  (upstream) modes [9]. In the presence of disorder and strong electrostatic inter-mode interaction (parametrized by a single parameter  $\Delta \rightarrow 1$ ), these bare modes renormalize to one ballistic downstream charge mode with  $G = \frac{2}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$  and one ballistic upstream neutral mode only at the low-temperature  $(T \rightarrow 0)$  and infinite-edge-length  $(L \to \infty)$  limit [10]. However, for

finite length and at finite temperature, a robust  $G = \frac{2}{3} \frac{e^2}{h}$ h requires full equilibration among the bare modes leading to incoherent transport [7, 8, 11]. In the opposite limit of coherent, non-equilibrated edge transport, one finds [7]  $G = \frac{4}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$ . Experimental observation of the crossover from  $G = \frac{4}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$  (entirely non-equilibrated) to  $G = \frac{2}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$  (fully equilibrated) has so sofar been reported only in a GaAs/AlGaAs based device [12]. The corresponding crossover length scale  $\ell_{\text{eq}}^C$  defines the electrical equilibration length. Likewise, the thermal equilibration length  $\ell_{\text{eq}}^H$  defines the crossover from a thermally non-equilibrated edge with thermal conductance  $G_Q = (n_d + n_u)\kappa_0 T$  to the topologically constrained and equilibrated thermal conductance  $G_Q = |n_d - n_u| \kappa_0 T$ . For  $\nu = \frac{2}{3}$  (where  $n_d = n_u = 1$ ) and its cousin states,  $\nu = \frac{5}{3}$  and  $\frac{8}{3}$ , this topology-dictated  $G_Q/\kappa_0 T$  is 0, 1, and 2, respectively. For  $\nu = \frac{2}{3}$ , the zero value is expected with increasing L as  $G_Q \sim \ell_{\text{eq}}^H/L$ , signalling heat diffusion [7, 8]. To date, experimental studies of thermal transport on complex FQH edges have been performed only in GaAs/AlGaAs based structures [5, 6], including  $\nu = \frac{2}{3}$ , and yielded values of  $G_Q$  consistent with the equilibrated regime. However, similar to the electrical conductance, an experimental manifestation of the dichotomy between equilibrated and non-equilibrated values of heat conductance on complex FQH edges is



Figure 1. Equilibration, Device schematic and QH response. (a) Left panel: voltage (top) and temperature (bottom) profile in colours with changing intensity along the edge for  $L \gg \ell_{\rm eq}^C$ ;  $\ell_{\rm eq}^H$ . In this limit, G is  $\frac{2}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$  and  $G_Q$  goes to zero diffusively. Right panel: voltage and temperature profile in limit  $\ell_{eq}^C \ll L \ll \ell_{eq}^H$  realized at  $\Delta \longrightarrow 1$ . While G is still  $\frac{2}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$ , one has now  $G_Q = 2\kappa_0 T$ . Solid and dashed lines correspond to the downstream and upstream eigenmodes, respectively. (b) Schematic of device with measurement setup. The device is set in the integer QH regime at  $\nu = 1$ . An injected current  $I_s$  (black line) is absorbed in the floating reservoir (red contact) and terminates into two cold grounds. The electrical and thermal conductances are measured at low frequency (228 Hz) and high frequency (∼ 758kHz with a LCR resonant circuit), respectively. (c) The blue line is the  $G_S$  ( $I_S/V_S$ ) as a function of  $V_{BG}$  at  $B = 10T$  for the D1 device. The red and black lines are the measured resistances (right y axis) at the T and R contacts, respectively. The robust fractional plateaus at  $\frac{5}{3} \frac{e^2}{h}$  $\frac{e^2}{h}, \frac{7}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$ ,  $\frac{8}{3} \frac{e^2}{h}$  with weaker plateau  $\sim \frac{4}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$  clearly visible. (d) The conductance measured in two probe (black), three probe (blue) and four probe (red) configurations are plotted for the D3 device. The inset show the contact positions. The first number in the subscript of I corresponds to current fed contact and the remaining numbers label grounded contacts. The same notation is used for voltage  $(V)$  measurements.

missing. In this context, a different system like bilayer graphene (BLG) with more degrees of freedom (valley and orbital) together with unprecedented universal edge profile [13, 14] due to atomically sharp confining potential are ideal platforms to study the thermal transport. For electron-like FQH edges in this system (with only downstream modes), topology dictated and universal thermal conductance values were found [15], but no measurements have so far been performed for complex hole-conjugate FQH edges.

Here, we report measurements of the thermal and

electric conductance of a variety of QH phases, realized in hBN encapsulated graphite gated BLG devices, for both electron and hole doping, using sensitive noise thermometry [5, 6, 15, 16], where all the symmetries (spin, valley and orbitals) are broken [17– 19. For integer QH  $(\nu = 1, 2, 3, 4)$  and electronlike FQH states  $(\nu = \frac{4}{3}, \frac{7}{3})$  we obtain the expected values for  $G \left(1 \frac{e^2}{h}\right)$  $\frac{e^2}{h}, 2\frac{e^2}{h}$  $\frac{e^2}{h}, 3\frac{e^2}{h}$  $\frac{e^{2}}{h},4\frac{e^{2}}{h}$  $\frac{e^2}{h}, \frac{4}{3} \frac{e^2}{h}$  $\frac{e^2}{h}, \frac{7}{3} \frac{e^2}{h}$  $\frac{e^2}{h}$ , respectively) and  $G_Q$  (within accuracy of 5%,  $1\kappa_0 T, 2\kappa_0 T, 3\kappa_0 T$ ,  $4\kappa_0T, 2\kappa_0T, 3\kappa_0T$ , respectively). For the hole-conjugate

phases  $\nu = \frac{5}{3}$  and  $\frac{8}{3}$ , G shows expected values  $\left(\frac{5}{3}\frac{e^2}{h}\right)$  $\frac{e^2}{h}$  and  $\frac{8}{3} \frac{e^2}{h}$  $\frac{\partial \xi}{\partial h}$ , respectively), corresponding to electrically equilibrated edges. At the same time, and most remarkably,  $G_{\mathcal{O}}$  is found to be  $3\kappa_0 T$  and  $4\kappa_0 T$ , respectively, corresponding to thermally non-equilibrated edges. Our results of thermal conductance on FQH states for different valleys and orbitals further suggest a universality; a topology dictated  $G_Q$  for electron-like FQH states  $(\frac{4}{3}, \frac{7}{3})$  but entirely non-equilibrated  $G_Q$  for holeconjugate  $\text{FQH}\text{ states }(\frac{5}{3}, \frac{8}{3})$ . To explain the striking contrast between electric and thermal equilibration for holeconjugate FQH states, we present a theoretical analysis of edge equilibration in the strong interaction limit [20]. In the limit of  $\Delta \to 1$  we find that, while  $\ell_{\text{eq}}^C$  remains finite,  $\ell_{\text{eq}}^{H}$  diverges as  $1/(\Delta - 1)$ , indicating vanishing thermal equilibration. This gives rise to a new regime  $\ell_{\text{eq}}^C \ll L \ll \ell_{\text{eq}}^H$  observed here; in Fig. 1a we contrast it to the regime of fully equilibrated transport,  $\ell_{\rm eq}^C$ ;  $\ell_{\rm eq}^H \ll L$ .

For the thermal conductance measurement, we used two bottom graphite gated devices (D1 and D2), where the graphene was encapsulated between two hBN layers, each with thickness of  $\sim$  20 nm. The device fabrication is described in the Supplemental Material (SM) ([19]). Similar to our previous work [15], our devices consist of a floating metallic reservoir in the middle, connected to edge channels on both sides, as shown schematically in Fig. 1(b) [15]. The distances from the floating contact to the transverse contacts and cold grounds in Fig. 1(b) were  $\sim 3\mu m$  (4 $\mu$ m) and  $\sim 6\mu m$  (8 $\mu$ m) for D1 (D2), respectively (see [19] for optical images). The electrical conductance was measured using standard lock-in technique whereas the thermal conductance was measured with noise thermometry  $[5, 6, 15, 16]$  ([19]). In Fig. 1(c), the blue curve represents  $G_S$   $(I_S/V_S)$  measured at the source contact  $(S)$  for the D1 device as a function of the bottom graphite gate voltage  $(V_{BG})$ .

Plateaus appear at  $\nu = \frac{5}{3}, \frac{7}{3}$  and  $\frac{8}{3}$  along with the integer QH plateaus at  $\nu = 1, 2$ , and 3. Similarly, for the D2 device, plateaus appear at  $\nu = \frac{4}{3}, \frac{7}{3}$  and  $\frac{8}{3}$  ([19] Fig. S6). In Fig. 1c, the red (black) curve shows the measured resistance  $R_T = V_T / I_S (R_R = V_R / I_S)$  at the T  $(R)$  contact along the transmitted (reflected) path from the floating contact (D1). Measured resistances along these paths are exactly half of the resistance measured at the S contact, which strongly suggest that the injected current is equally divided from the floating contact to both sides of the graphene channel. The resistance values at the  $S, R$ and T contacts for  $\nu = \frac{5}{3}$  and  $\frac{8}{3}$  are consistent with the charge equilibration of the bare modes along the propagation length. To further confirm the charge equilibration, we measure the conventional two-probe electrical conductance of  $\nu = \frac{2}{3}$  in another device (D3 with  $L \sim 5 - 6 \mu m$ ) with three-probe and four-probe configurations. In Fig. 1d, the quantized value is fixed at  $\sim$  39kΩ. By contrast, if there was no charge equilibration, the resistance values

obtained using the Landauer Büttiker model [21] for our devices will be quite different [19].

In order to measure the thermal conductance, a DC current  $(I<sub>S</sub>)$ , injected at the S contact (Fig. 1b), flows towards the floating reservoir and the outgoing current splits into two equal parts to the cold grounds. The power dissipation at the floating reservoir due to joule heating is  $J_Q = \frac{I_S^2}{4\nu G_0}$  (SM [19]), [15], and thus the electrons in the floating reservoir will be heated to a new steady state temperature  $(T_M)$ , determined by the following heat balance relation [5, 6, 15, 16, 22, 23]

$$
J_Q = J_Q^e(T_M, T_0) + J_Q^{e-ph}(T_M, T_0)
$$
 (1)

$$
J_Q = 0.5N\kappa_0(T_M^2 - T_0^2) + J_Q^{e-ph}(T_M, T_0)
$$
 (2)

Here,  $J_Q^e(T_M, T_0)$  is the electronic contribution of the heat current via N chiral edge modes, and  $J_Q^{e-ph}(T_M, T_0)$ is the heat loss via electron-phonon coupling. The  $T_M$ is obtained by measuring the excess thermal noise;  $S_I = \nu k_B (T_M - T_0) G_0$  [5, 6, 15, 16, 22, 24–26], along the outgoing edge channels as shown in Fig. 1b. Fig. 2a shows the measured excess thermal noise  $S_I$  as a function of current  $I_S$  for  $\nu = 1$  (red), 2 (black), and 3 (blue) (D1). The noise and current axes of Fig. 2a are converted to  $J_Q$  and  $T_M$ , and plotted in Fig. 2b. To extract  $G_Q$  for each filling factor, we have plotted  $J_Q$  as a function of  $T_M^2 - T_0^2$  in Fig. 2c. The solid circles represent the experimental data, while the solid lines are the linear fits of  $G_Q$  with 0.99, 1.96, and  $3.01\kappa_0T$  for  $\nu =1$ , 2 and 3, respectively. Similarly, for device D2,  $G_Q$  was found to be ∼ 0.99, 2.05, 3.04 and  $3.96\kappa_0 T$  for  $\nu =1, 2, 3$  and 4, respectively ([19] Fig. S7), which shows an excellent match with its expected theoretical values. Note that  $J^{e-ph}$  was negligible up to  $T_M \sim 60 \text{mK}$  and also, heat Coulomb blockade [27] was expected to be absent for our graphite gated devices [19].

Fig. 3a shows  $S_I$  as a function of  $I_S$  for  $\nu = \frac{5}{3}$  (red),  $\frac{7}{3}$  (black) and  $\frac{8}{3}$  (blue) for D1. Experimental curves for  $7/3$  and 8/3 are shifted vertically by  $1 \times 10^{-29} A^2/Hz$  and  $3\times10^{-29}A^2/Hz$  for clarity. From these raw data, the  $T_M$ was extracted as a function of  $J_Q$  [19]. In Fig. 3b,  $J_Q$  is plotted as a function of  $T_M^2 - T_0^2$  as shown by the coloured circles, and the solid lines are the theoretical curves for  $G_Q = 1\kappa_0 T$  (magenta),  $2\kappa_0 T$  (brown),  $3\kappa_0 T$  (red) and  $4\kappa_0 T$  (blue). The linear fittings to the measured data in Fig. 3b gives  $G_Q \sim 3.03$ , 2.96, and  $4.03\kappa_0 T$  for  $\frac{5}{3}$ ,  $\frac{7}{3}$  and  $\frac{8}{3}$ , respectively. Similarly,  $G_Q \sim 1.96$ , 3.01, and 3.94 $\kappa_0 T$ for  $\frac{4}{3}$ ,  $\frac{7}{3}$  and  $\frac{8}{3}$ , respectively, for device D2 ([19] Fig. S8). For the particle-like states  $\frac{4}{3}$  and  $\frac{7}{3}$ , the measured value of  $G_{\mathcal{O}}$  is in excellent agreement with the expected theoretical values. However, for the hole-like FQH states  $\frac{5}{3}$  and  $\frac{8}{3}$ , the measured  $G_Q$  strikingly matches with  $(n_d+n_u)\kappa_0T$ rather than the expected topological quantum number of



Figure 2. Thermal conductance for integer QH states. (a) Excess thermal noise  $S_I$  as a function of source current  $I_S$  at  $\nu = 1$  (red), 2 (black) and 3 (blue). (b) The temperature  $T_M$  of the floating contact as a function of the dissipated power  $J_Q$ for  $\nu = 1$  (red), 2 (black) and 3 (blue), respectively. (c)  $J_Q$  (solid circles) as a function of  $T_M^2 - T_0^2$  for  $\nu = 1$  (red), 2 (black) and 3 (blue), respectively. Solid lines are linear fits with  $G_Q = 0.99$ , 1.96 and  $3.01\kappa_0T$  for  $\nu = 1$ , 2 and 3, respectively.



Figure 3. Thermal conductance for fractional QH states. (a)  $S_I$  as a function of  $I_S$  at  $\nu = 5/3$  (red), 7/3 (black) and  $8/3$  (blue). Experimental curves for 7/3 and  $8/3$  are shifted vertically by  $1 \times 10^{-29} A^2/Hz$  and  $3 \times 10^{-29} A^2/Hz$ . (b)  $J_Q$  (solid circles) as a function of  $T_M^2 - T_0^2$  for  $\nu = 5/3$  (red), 7/3 (black) and 8/3 (blue). The solid magenta, brown, red and blue lines represent  $G_Q = 1\kappa_0 T$ ,  $2\kappa_0 T$ ,  $3\kappa_0 T$  and  $4\kappa_0 T$ , respectively. The linear fits of the solid circles give  $G_Q = 3.03$ , 2.96 and  $4.03\kappa_0 T$ for  $\nu = 5/3, 7/3$  and  $8/3$ , respectively. (c)  $\lambda = \Delta J_Q/(0.5\kappa_0)$  as a function of  $T_M^2$  for  $\Delta \nu = 5/3 - 1$  (red) and  $\Delta \nu = 8/3 - 2$ (black), where  $\Delta J_Q = J_Q(\nu_i, T_M) - J_Q(\nu_j, T_M)$ . Solid lines represent linear fits. Extracted values of  $G_Q$  of the 2/3-like FQH states are  $2.02\kappa_0 T$  and  $2.06\kappa_0 T$  for  $\Delta \nu = 5/3 - 1$  and  $\Delta \nu = 8/3 - 2$ , respectively.

 $|n_d-n_u|\kappa_0T = 1\kappa_0T$ , and  $2\kappa_0T$ , respectively. In Fig. 3c, we plot  $\lambda = \Delta J_Q/(0.5\kappa_0)$  as a function of  $T_{M_\lambda}^2$  for two different configurations of  $\Delta \nu = \frac{5}{3} - 1$  (red) and  $\frac{8}{3} - 2$  (black) to extract the contribution of the partially filled Landau level with  $\nu = \frac{2}{3}$  out of the data for  $\frac{5}{3}$  and  $\frac{8}{3}$ . Linear fits give  $2.02\kappa_0T$  and  $2.06\kappa_0T$ , respectively, for  $G_Q$  of the  $\nu =$  $\frac{2}{3}$  state. For the D2 device, the fit yields  $1.99\kappa_0 T$  ([19] Fig. S8). It is worth to mention here that the thermal conductance of  $\frac{7}{3}$  and  $\frac{8}{3}$  states observed in hole doped (device D1) and in electron doped (device D2) regime are the same, irrespective of the different orbital nature of their wave-functions, which is  $N=1(0)$  in hole(electron) doped regime[17–19]. In fact, the extracted thermal conductance of  $\frac{2}{3}$  like state from  $\frac{5}{3}$  and  $\frac{8}{3}$  (Fig. 3(c)) is also the same, irrespective of the different orbital nature of wave-functions, which is  $N=1(0)$  for  $\frac{5}{3}(\frac{8}{3})$ . This establishes the universality of our results.

The observed values of the thermal conductance for  $\nu = \frac{5}{3}$  and  $\frac{8}{3}$  imply essentially vanishing thermal equilibration between counter-propagating modes. To explain this, we consider a model of counter-propagating 1 and  $\frac{1}{3}$ modes in the uppermost Landau level. In the presence of inter-channel interactions, this level consists of two emergent, counter-propagating eigenmodes. Their dimensionless charge conductances are  $g_{\pm} = (\Delta \pm 1)/3$ . Importantly, their dimensionless heat conductances are unity, independent of  $\Delta$ . Tunneling facilitated by random disorder leads to equilibration between these modes. Calculating the charge and heat tunneling currents, we derive thermal  $(\ell_{\text{eq}}^H)$  and charge  $(\ell_{\text{eq}}^C)$  equilibration lengths [19];

$$
\ell_{\text{eq}}^{H/C} \propto \mathcal{C}^{H/C}(\Delta) T^{2-2\Delta}, \quad \mathcal{C}^H(\Delta) \sim \frac{1}{\Delta - 1}, \quad \mathcal{C}^C(\Delta) \sim 1,
$$
\n(3)

where we have displayed only the dependence on the temperature T and  $\Delta$ . Our key observation is that the coefficient  $\mathcal{C}^H(\Delta)$  diverges for  $\Delta \to 1$ , implying a very large  $\ell_{\text{eq}}^H$ . This happens because the tunneling current between eigenmodes is proportional to  $\Delta-1$ . The region  $\Delta$  close to 1 corresponds to very strong interactions. We argue that the sharp confining potential of our graphene devices, where the screening graphite gate is separated from the electron gas of graphene by a thin insulating  $hBN$  layer ( $∼ 10 - 20$  nm) [13, 14, 28, 29], favors this regime in contrast to the shallow confining potential in GaAs/AlGaAs devices [5, 6]. For  $\ell_{\mathrm{eq}}^C$ , the smallness of the tunneling current is compensated by the smallness of the charge conductance of one of the eigenmodes  $(g_$ ). The eigenmode conductances determine the effect of tunneled charge on the local voltages. Tunneling of a finite charge to the "almost neutral" chiral mode results in an enhanced effect on the local voltage of the mode, facilitating easier equilibration of the local chemical potentials. Technically, this will compensate the  $\Delta - 1$  factor of the tunneling current, leading to  $\mathcal{C}^C(\Delta) \sim 1$  (the same result for  $\ell_{\text{eq}}^C$  is also obtained [30] by explicitly considering electrostatics of fractionalization-renormalized tunneling.) As a result, for  $\Delta$  close to 1,  $\ell_{\text{eq}}^C \ll \ell_{\text{eq}}^H$ , which creates a broad regime of system sizes  $\ell_{\text{eq}}^C \ll L \ll \ell_{\text{eq}}^H$  thereby explaining the experimental observations of efficient charge equilibration but vanishing thermal equilibration.

In conclusion, the findings of this work are a remarkable manifestation of a transport regime with partial equilibration: the charge transport is in an equilibrated regime, while the heat transport is non-equilibrated irrespective of the different symmetry nature of wavefunctions. Both quantities, in the asymptotic limits of an equilibrated/non-equilibrated edge, respectively, are determined by the edge quantum numbers. We expect that such regimes should be relevant also to other FQH states and materials. In fact, several proposed mechanisms for explaining the observed heat conductance  $\frac{5}{2}\kappa_0 T$  at  $\nu = 5/2$  involve patterns of partial equilibration within the (non-abelian) anti-Pfaffian state [31–34]. We envisage future work exploring the influence of partial equilibration on noise, decoherence, and FQH interferometry.

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